

Data Sheet No. PD60029 revJ IR2155&(PbF) (NOTE: For new designs, we recommend IR's new products IR2153 and IR21531)

## SELF-OSCILLATING HALF-BRIDGE DRIVER

#### **Features**

- Floating channel designed for bootstrap operation Fully operational to +600V Tolerant to negative transient voltage dV/dt immune
- Undervoltage lockout
- Programmable oscillator frequency

$$f = \frac{1}{1.4 \times (\mathsf{R}_{\mathsf{T}} + 150\Omega) \times \mathsf{C}}$$

- Matched propagation delay for both channels
- Micropower supply startup current of 125 µA typ.
- Low side output in phase with RT
- Available in Lead-Free

#### Description

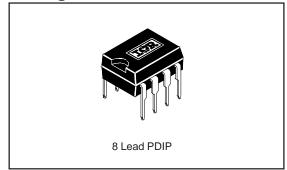
The IR2155 is a high voltage, high speed, selfoscillating power MOSFET and IGBT driver with both high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The front end features a programmable oscillator which is similar to the 555 timer. The output drivers feature a high pulse current buffer stage and an internal deadtime designed for minimum driver crossconduction. Propagation delays for the two channels are matched to simplify use in 50% duty cycle applications. The floating channel can be used to drive an N-channel power

#### **Typical Connection**

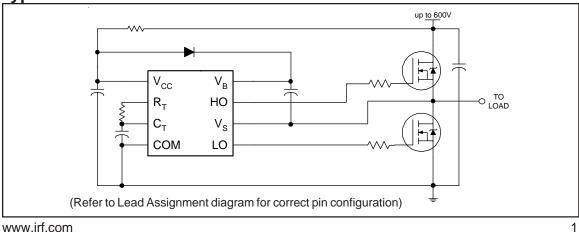
#### Product Summary

Voffset	600V max.
Duty Cycle	50%
IO+/-	210 mA / 420 mA
Vout	10 - 20V
Deadtime (typ.)	1.2 µs

#### Package



MOSFET or IGBT in the high side configuration that operates off a high voltage rail up to 600 volts.



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### **Absolute Maximum Ratings**

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Parameter		Va					
Symbol	Definition		Min.	Max.	Units		
VB	High Side Floating Supply Voltage		-0.3	625			
Vs	High Side Floating Supply Offset Voltage		V <sub>B</sub> - 25	V <sub>B</sub> + 0.3			
V <sub>HO</sub>	High Side Floating Output Voltage		V <sub>S</sub> - 0.3	V <sub>B</sub> + 0.3	V		
V <sub>LO</sub>	Low Side Output Voltage		-0.3	V <sub>CC</sub> + 0.3	V		
V <sub>RT</sub>	R <sub>T</sub> Voltage		-0.3	V <sub>CC</sub> + 0.3			
V <sub>CT</sub>	C <sub>T</sub> Voltage		-0.3	V <sub>CC</sub> + 0.3			
ICC	Supply Current (Note 1)		_	25	mA		
I <sub>RT</sub>	R <sub>T</sub> Output Current		-5	5	IIIA		
dV <sub>s</sub> /dt	Allowable Offset Supply Voltage Transient		_	50	V/ns		
PD	Package Power Dissipation @ $T_A \le +25^{\circ}C$	(8 Lead DIP)	_	1.0	14/		
		(8 Lead SOIC)		0.625	W		
R <sub>0JA</sub>	Thermal Resistance, Junction to Ambient	(8 Lead DIP)	_	125	°C/W		
	(8 Lead SOIC			200	C/vv		
TJ	Junction Temperature		_	150			
Τ <sub>S</sub>	Storage Temperature		-55	150	°C		
TL	Lead Temperature (Soldering, 10 seconds)		—	300			

#### **Recommended Operating Conditions**

The Input/Output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The  $V_S$  offset rating is tested with all supplies biased at 15V differential.

	Parameter	Va			
Symbol	Definition	Min.	Max.	Units	
VB	High Side Floating Supply Absolute Voltage	V <sub>S</sub> + 10	V <sub>S</sub> + 20		
Vs	High Side Floating Supply Offset Voltage	_	600	v	
V <sub>HO</sub>	High Side Floating Output Voltage	VS	VB	v	
VLO	Low Side Output Voltage	0	Vcc		
ICC	Supply Current (Note 1)	_	5	mA	
T <sub>A</sub>	Ambient Temperature	-40	125	°C	

Note 1: Because of the IR2155's application specificity toward off-line supply systems, this IC contains a zener clamp structure between the chip V<sub>CC</sub> and COM which has a nominal breakdown voltage of 15.6V. Therefore, the IC supply voltage is normally derived by forcing current into the supply lead (typically by means of a high value resistor connected between the chip V<sub>CC</sub> and the rectified line voltage and a local decoupling capacitor from V<sub>CC</sub> to COM) and allowing the internal zener clamp circuit to determine the nominal supply voltage. Therefore, this circuit should not be driven by a DC, low impedance power source of greater than V<sub>CLAMP</sub>.

#### International **TOR** Rectifier **Dynamic Electrical Characteristics**

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#### $V_{BIAS}$ (V<sub>CC</sub>, V<sub>BS</sub>) = 12V, C<sub>L</sub> = 1000 pF and T<sub>A</sub> = 25°C unless otherwise specified.

	Parameter	Value				
Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
tr	Turn-On Rise Time		80	120	ns	
tr	Turn-Off Fall Time	—	40	70	115	
DT	Deadtime	0.50	1.20	2.25	μs	
D	R <sub>T</sub> Duty Cycle	48	50	52	%	

### **Static Electrical Characteristics**

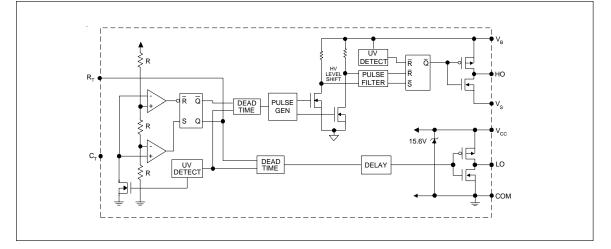
 $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 12V,  $C_L$  = 1000 pF,  $C_T$  = 1 nF and  $T_A$  = 25°C unless otherwise specified. The  $V_{IN}$ ,  $V_{TH}$  and  $I_{IN}$  parameters are referenced to COM. The  $V_O$  and  $I_O$  parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

	Parameter Value					
Symbol	Definition	Min.	Тур.	Max.	Units	<b>Test Conditions</b>
fosc	Oscillator Frequency	19.4	20.0	20.6	kHz	R <sub>T</sub> = 35.7 kΩ
		94	100	106	КПД	R <sub>T</sub> = 7.04 kΩ
V <sub>CLAMP</sub>	V <sub>CC</sub> Zener Shunt Clamp Voltage	14.4	15.6	16.8		$I_{CC} = 5 \text{ mA}$
V <sub>CT+</sub>	2/3 V <sub>CC</sub> Threshold	7.8	8.0	8.2	V	
V <sub>CT-</sub>	1/3 V <sub>CC</sub> Threshold	3.8	4.0	4.2		
V <sub>CTUV</sub>	C <sub>T</sub> Undervoltage Lockout		20	50		$2.5V < V_{CC} < V_{CCUV}$
V <sub>RT+</sub>	R <sub>T</sub> High Level Output Voltage, V <sub>CC</sub> - R <sub>T</sub>		0	100		I <sub>RT</sub> = -100 μA
			200	300		I <sub>RT</sub> = -1 mA
V <sub>RT-</sub>	R <sub>T</sub> Low Level Output Voltage		20	50	mV	I <sub>RT</sub> = 100 μA
			200	300	1110	I <sub>RT</sub> = 1 mA
V <sub>RTUV</sub>	RT Undervoltage Lockout, V <sub>CC</sub> - R <sub>T</sub>		0	100		$2.5V < V_{CC} < V_{CCUV}$
V <sub>OH</sub>	High Level Output Voltage, V <sub>BIAS</sub> - V <sub>O</sub>			100		$I_{O} = 0A$
V <sub>OL</sub>	Low Level Output Voltage, V <sub>O</sub>			100		$I_{O} = 0A$
I <sub>LK</sub>	Offset Supply Leakage Current			50		$V_{\rm B} = V_{\rm S} = 600 V$
I <sub>QBS</sub>	Quiescent V <sub>BS</sub> Supply Current		70	150		
I <sub>QBSUV</sub>	Micropower V <sub>BS</sub> Supply Startup Current		55	125	μA	
I <sub>QCC</sub>	Quiescent V <sub>CC</sub> Supply Current		500	1000		
IQCCUV	Micropower V <sub>CC</sub> Supply Startup Current		70	150		
I <sub>CT</sub>	C <sub>T</sub> Input Current		0.001	1.0		
V <sub>BSUV+</sub>	V <sub>BS</sub> Supply Undervoltage Positive Going	7.7	8.4	9.2		
	Threshold				v	
V <sub>BSUV-</sub>	V <sub>BS</sub> Supply Undervoltage Negative Going	7.3	8.1	8.9	v v	
	Threshold					
V <sub>BSUVH</sub>	V <sub>BS</sub> Supply Undervoltage Lockout Hysteresis	100	400	—	mV	
V <sub>CCUV+</sub>	V <sub>CC</sub> Supply Undervoltage Positive Going	7.7	8.4	9.2		
	Threshold				v	
V <sub>CCUV-</sub>	V <sub>CC</sub> Supply Undervoltage Negative Going	7.4	8.1	8.9		
	Threshold					
V <sub>CCUVH</sub>	V <sub>CC</sub> Supply Undervoltage Lockout Hysteresis	200	400	—	mV	
I <sub>O+</sub>	Output High Short Circuit Pulsed Current	210	250		mA	$V_{O} = 0V$
I <sub>0-</sub>	Output Low Short Circuit Pulsed Current	420	500	_		V <sub>O</sub> = 15V

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# International **tor** Rectifier

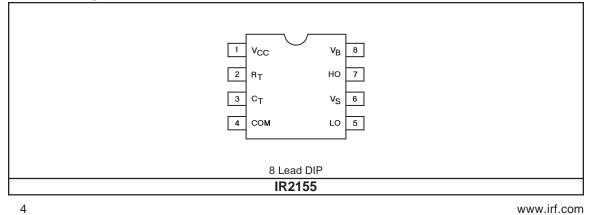
## IR2155&(PbF) Functional Block Diagram



## **Lead Definitions**

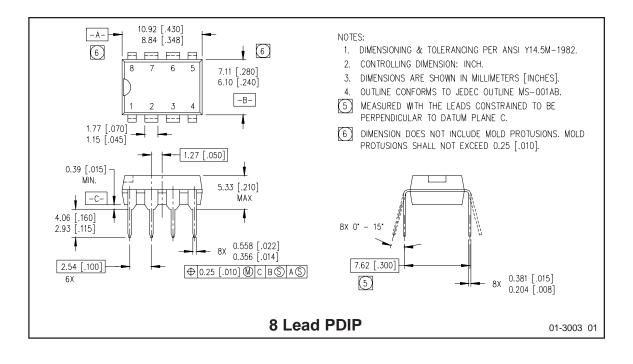
Le	ad			
Symbol	Description			
R <sub>T</sub>	Oscillator timing resistor input, in phase with LO for normal IC operation			
CT	Oscillator timing capacitor input, the oscillator frequency according to the following equation:			
	$f = \frac{1}{1.4 \times (R_{T} + 150\Omega) \times C_{T}}$			
	where $150\Omega$ is the effective impedance of the R <sub>T</sub> output stage			
VB	High side floating supply			
HO	High side gate drive output			
Vs	High side floating supply return			
V <sub>CC</sub>	Low side and logic fixed supply			
LO	Low side gate drive output			
COM	Low side return			

## Lead Assignments



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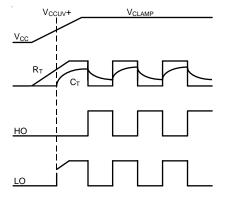


Figure 1. Input/Output Timing Diagram

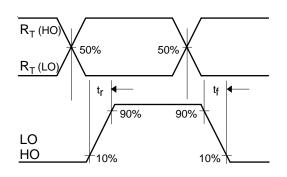


Figure 2. Switching Time Waveform Definitions

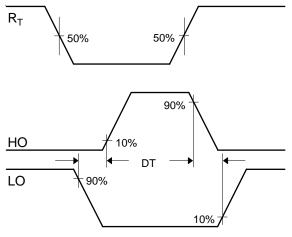
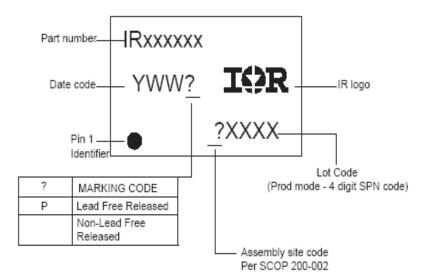


Figure 3. Deadtime Waveform Definitions

## LEADFREE PART MARKING INFORMATION



#### **ORDER INFORMATION**

Basic Part (Non-Lead	Free)	Lead-Free Part				
8-Lead PDIP IR2155	order IR2155	8-Lead PDIP IR2155	order IR2155PbF			

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